

**AVT-53663**  
 DC – 6000 MHz  
 InGaP HBT Gain Block



**Data Sheet**

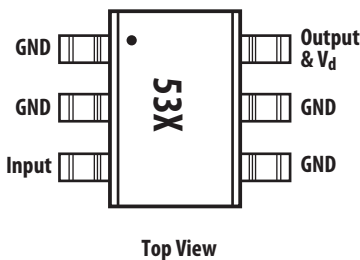
**Description**

Avago Technologies' AVT-53663 is an economical, easy-to-use, general purpose InGaP HBT MMIC gain block amplifier utilizing Darlington pair configuration housed in a 6-lead (SOT-363) surface mount plastic package.

The Darlington feedback structure provides inherent broad bandwidth performance, resulting in useful operating frequency up to 6 GHz. This is an ideal device for small-signal gain cascades or IF amplification.

AVT-53663 is fabricated using advanced InGaP HBT (Hetero-junction Bipolar Transistor) technology that offers state-of-the-art reliability, temperature stability and performance consistency.

**Component Image**



Notes:  
 Package marking provides orientation and identification  
 "53" = Device Code  
 "X" = Month of Manufacture  
 "•" = Pin 1

**Features**

- Small signal gain amplifier
- Operating frequency DC to 6 GHz
- Unconditionally stable
- 50 Ohm input & output
- Flat, Broadband Frequency Response up to 2 GHz
- Industry standard SOT-363
- Lead-free, RoHS compliant, Green

**Specifications**

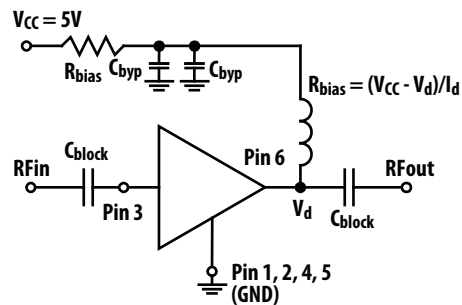
**2 GHz, 5V Vcc, 48mA (typical)**

- 19.5 dB Gain
- 15.1 dBm P1dB
- 26.5 dBm OIP3
- 3.2 dB NF
- 10 dB IRL and ORL

**Applications**

- Cellular / PCS / 3G base station
- Wireless Data / WLAN
- WiMAX / WiBRO
- CATV & Cable modem
- ISM

**Typical Biasing Configuration**



**Attention: Observe precautions for handling electrostatic sensitive devices.**

ESD Machine Model = 160 V  
 ESD Human Body Model = 2000 V  
 Refer to Avago Application Note A004R:  
 Electrostatic Discharge, Damage and Control.

## Absolute Maximum Rating<sup>[1]</sup> T<sub>A</sub>=25°C

Symbol	Parameter	Units	Absolute Max.
I <sub>d</sub>	Device Current	mA	80
P <sub>IN,MAX</sub>	CW RF Input Power	dBm	18
P <sub>DISS</sub>	Total Power Dissipation <sup>[3]</sup>	mW	327
T <sub>OPT</sub>	Operating Temperature	°C	-40 to 85
T <sub>J,MAX</sub>	Junction Temperature	°C	150
T <sub>STG</sub>	Storage Temperature	°C	-65 to 150

## Thermal Resistance

Thermal Resistance<sup>[2]</sup> θ<sub>jc</sub> = 184°C/W  
(I<sub>d</sub> = 48 mA, T<sub>c</sub> = 85°C)

Notes:

1. Operation of this device in excess of any of these limits may cause permanent damage.
2. Thermal resistance measured using Infrared measurement technique.
3. Ground lead temperature is 25°C. Derate 5.5mW/°C for T<sub>c</sub> > 90°C.

## Electrical Specifications<sup>[1]</sup>

T<sub>A</sub> = 25°C, Z<sub>o</sub> = 50 Ω, V<sub>CC</sub> = 5 V, R<sub>bias</sub> = 22 Ω, P<sub>in</sub> = -15 dBm (unless specified otherwise)

Symbol	Parameter and Test Condition	Frequency	Units	Min.	Typ.	Max.
I <sub>d</sub>	Device Current		mA	44.0	47.6	51.0
G <sub>p</sub>	Power Gain	900 MHz 2000 MHz	dB	18.0	21.8 19.5	21.0
OIP3 <sup>[2]</sup>	Output 3 <sup>rd</sup> Intercept Point	900 MHz 2000 MHz	dBm	25.0	28.9 26.5	
S11	Input Return Loss, 50Ω source	900 MHz 2000 MHz	dB		-16.5 -12.0	
S22	Output Return Loss, 50Ω load	900MHz 2000 MHz	dB		-17.3 -13.4	
S12	Reverse Isolation	900 MHz 2000 MHz	dB		-24.3 -24.7	
P1dB	Output Power at 1dB Gain Compression	900 MHz 2000 MHz	dBm		16.0 15.1	
NF	Noise Figure	900 MHz 2000 MHz	dB		2.9 3.2	

Notes:

1. Measurements obtained on CPWG line with reference plane at the ends of DUT leads (as shown in Figure 1).
2. OIP3 test condition: F<sub>RF1</sub> - F<sub>RF2</sub> = 10MHz with input power of -23 dBm per tone measured at worse side band.

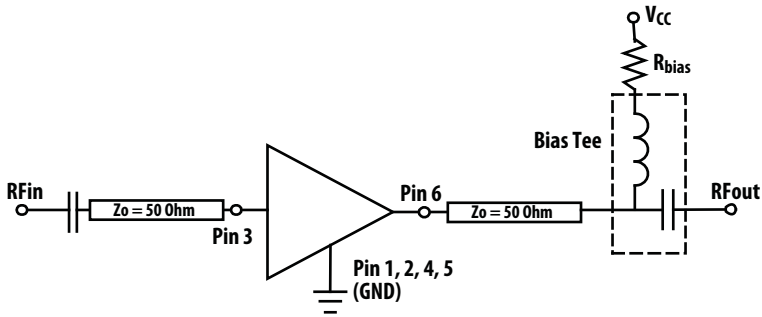


Figure 1. Block diagram of board used for  $I_d$ , Gain, OIP3, S11, S22, S12, OP1dB and NF measurements. Circuit losses have been de-embedded from actual measurements.

**Product Consistency Distribution Charts at 2 GHz,  $V_{cc} = 5$  V,  $R_{bias} = 22 \Omega$**

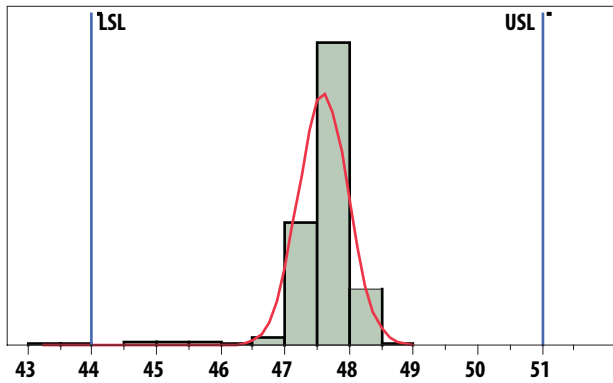


Figure 2.  $I_d$  (mA) distribution. LSL = 44.5, Nominal = 47.6, USL = 50.5

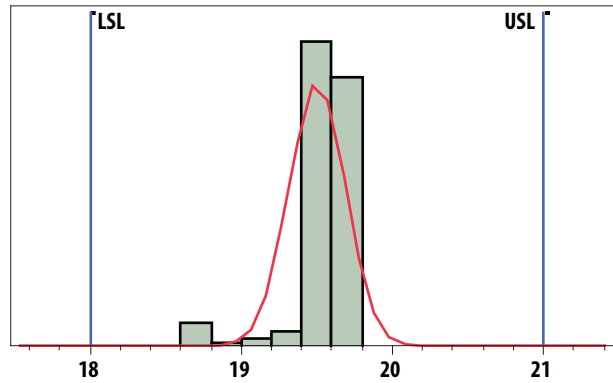


Figure 3. Gain (dB) distribution. LSL = 18, Nominal = 19.5, USL = 21

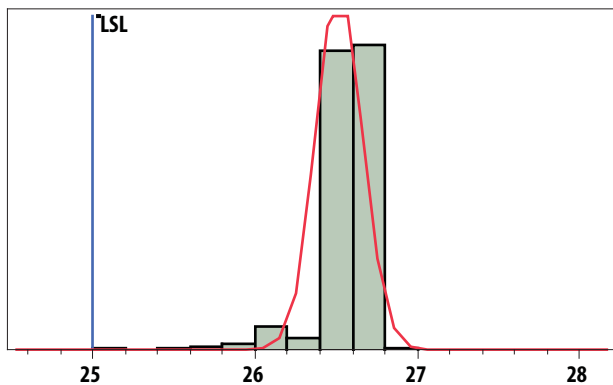


Figure 4. OIP3 (dBm) distribution. LSL = 25.5, Nominal = 26.6

Notes:

1. Statistical distribution determined from a sample size of 1500 samples taken from 3 different wafers from 2 wafer lots, measured on a production test board.
2. Future wafers allocated to this product may have typical values anywhere between the minimum and maximum specification limits.

## AVT-53663 Typical Performance Curves

$T_A = 25^\circ\text{C}$ ,  $Z_o = 50\ \Omega$ ,  $P_{in} = -15\ \text{dBm}$  (unless specified otherwise)

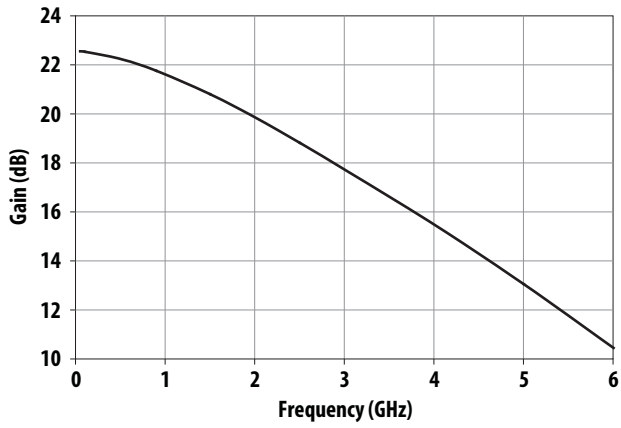


Figure 5. Gain vs Frequency at  $I_d = 48\text{mA}$

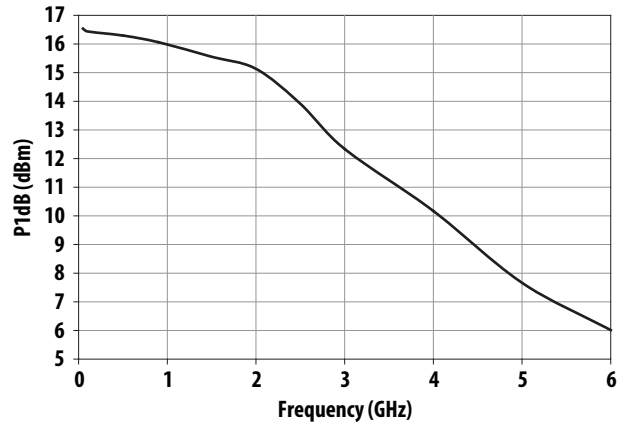


Figure 6. P1dB vs Frequency at  $I_d = 48\text{mA}$

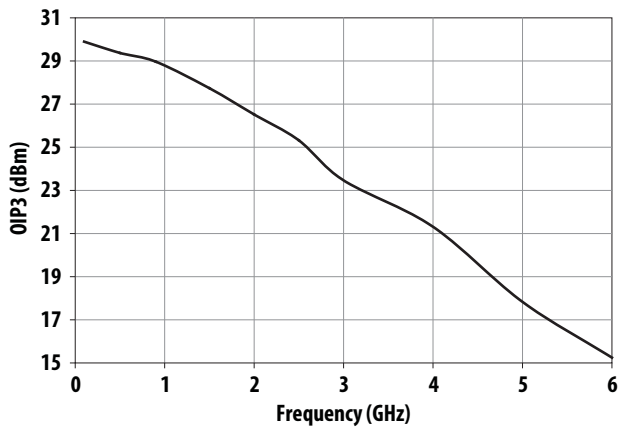


Figure 7. OIP3 vs Frequency at  $I_d = 48\text{mA}$ ,  $P_{in} = -23\text{dBm}$

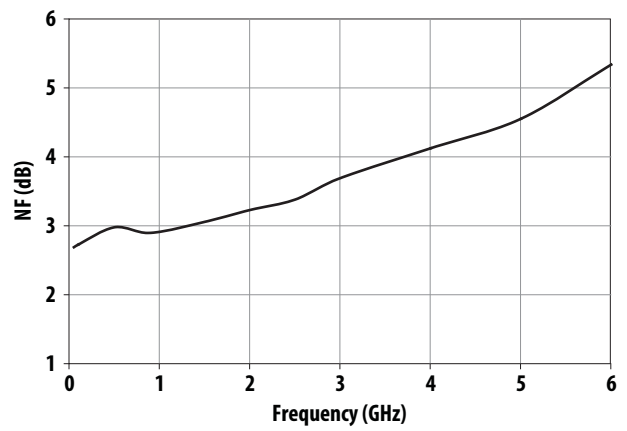


Figure 8. NF vs Frequency at  $I_d = 48\text{mA}$

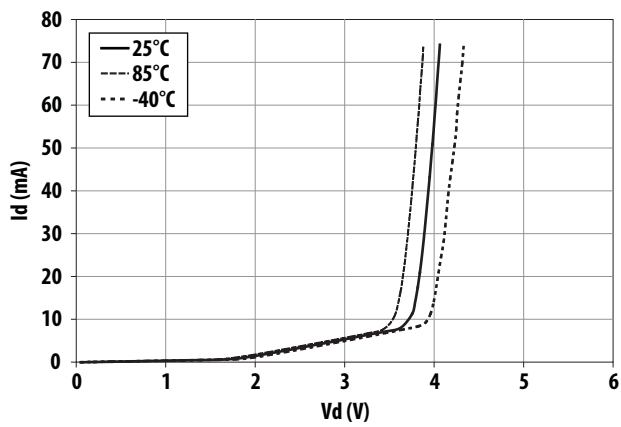


Figure 9.  $I_d$  vs  $V_d$  and Temperature

## AVT-53663 Typical Performance Curves

$T_A = 25^\circ\text{C}$ ,  $Z_o = 50 \Omega$ ,  $P_{in} = -15 \text{ dBm}$  (unless specified otherwise), continued

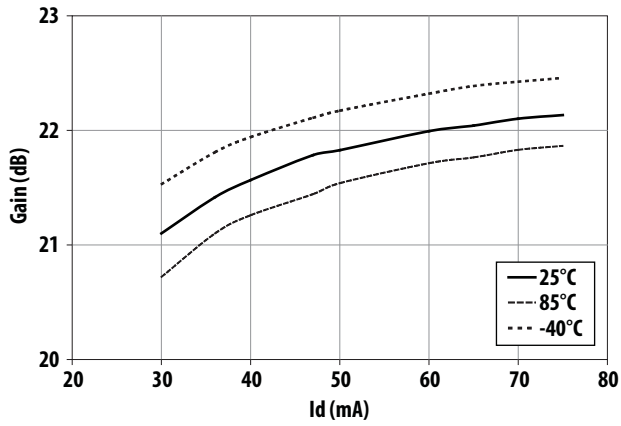


Figure 10. Gain vs  $I_d$  and Temperature at 900 MHz

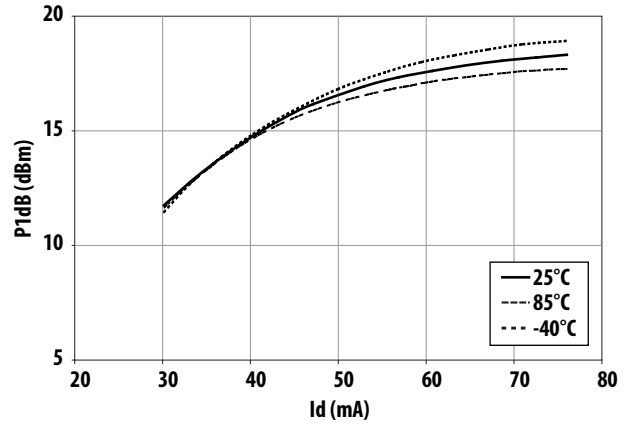


Figure 11. P1dB vs  $I_d$  and Temperature at 900 MHz

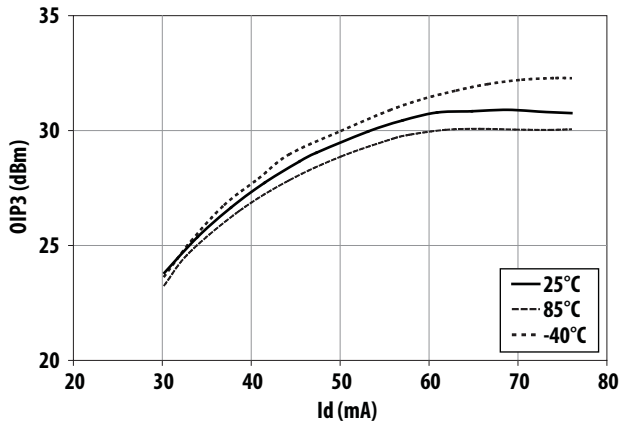


Figure 12. OIP3 vs  $I_d$  and Temperature at 900 MHz,  $P_{in} = -23 \text{ dBm}$

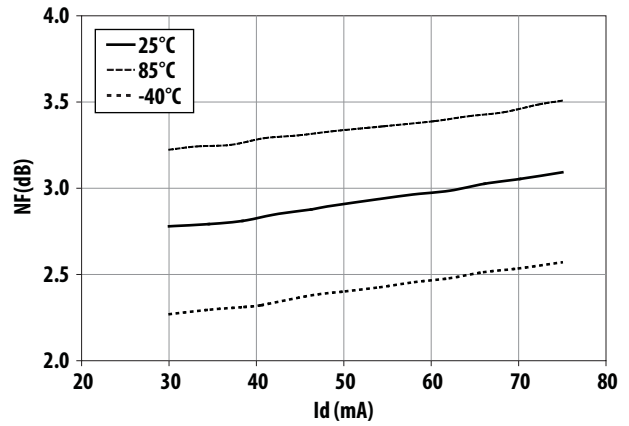


Figure 13. NF vs  $I_d$  and Temperature at 900 MHz

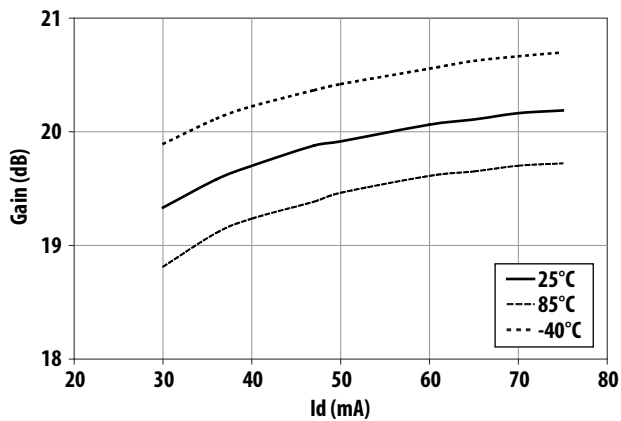


Figure 14. Gain vs  $I_d$  and Temperature at 2 GHz

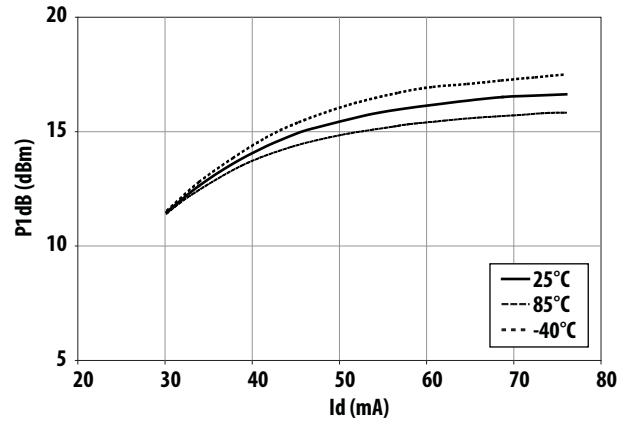


Figure 15. P1dB vs  $I_d$  and Temperature at 2 GHz

## AVT-53663 Typical Performance Curves

$T_A = 25^\circ\text{C}$ ,  $Z_o = 50 \Omega$ ,  $P_{in} = -15 \text{ dBm}$  (unless specified otherwise), continued

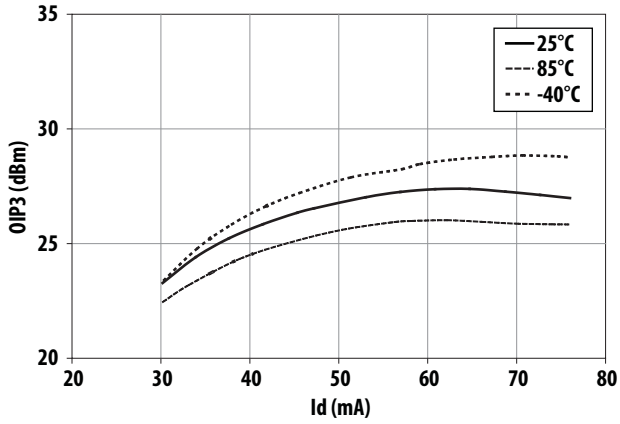


Figure 16. OIP3 vs  $I_d$  and Temperature at 2 GHz,  $P_{in} = -23\text{dBm}$

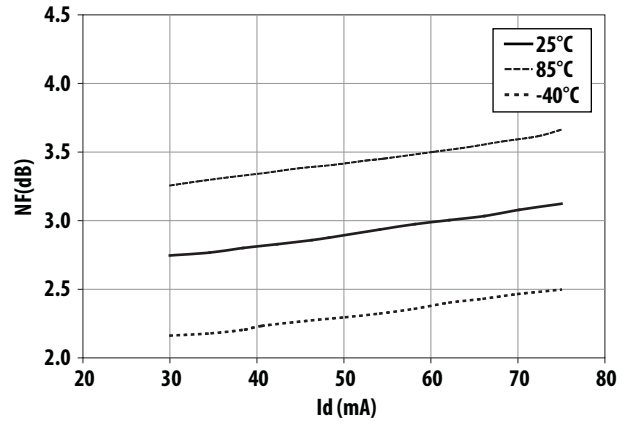


Figure 17. NF vs  $I_d$  and Temperature at 2 GHz

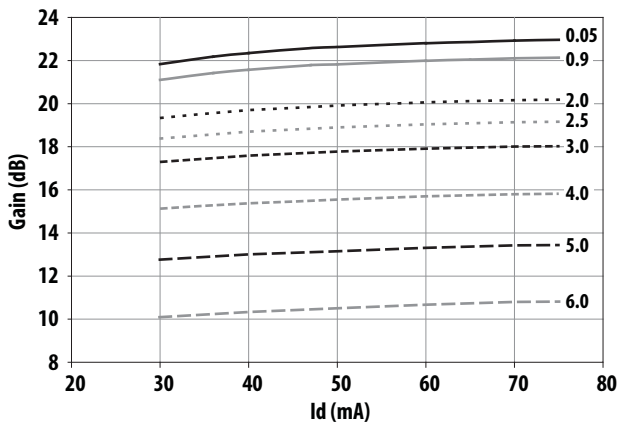


Figure 18. Gain vs  $I_d$  and Frequency (GHz)

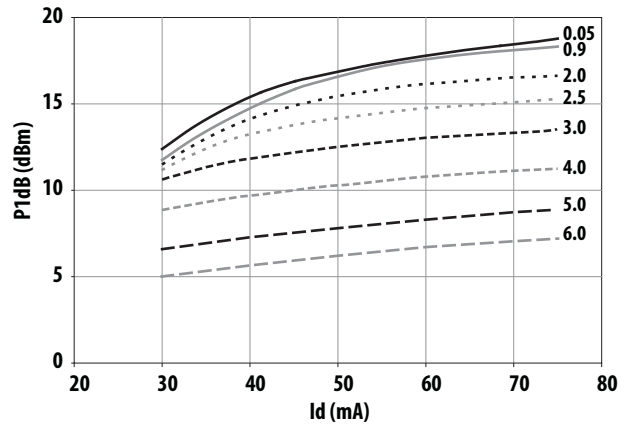


Figure 19. P1dB vs  $I_d$  and Frequency (GHz)

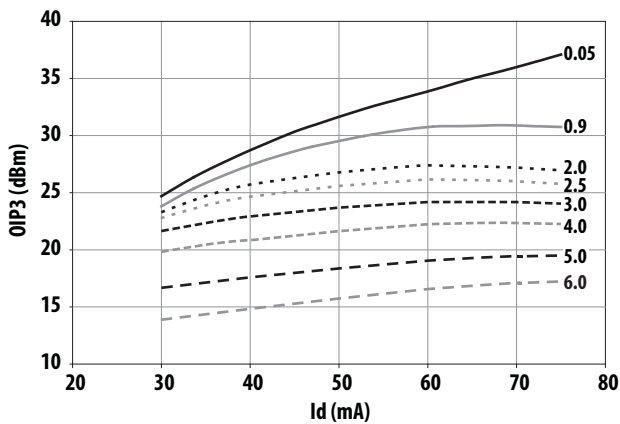


Figure 20. OIP3 vs  $I_d$  and Frequency (GHz),  $P_{in} = -23\text{dBm}$

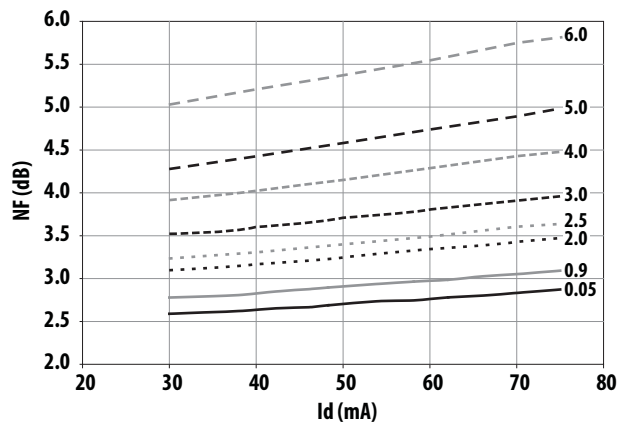


Figure 21. NF vs  $I_d$  and Frequency (GHz)

### AVT-53663 Typical Performance Curves

$T_A = 25^\circ\text{C}$ ,  $Z_o = 50\ \Omega$ ,  $P_{in} = -15\ \text{dBm}$  (unless specified otherwise), continued

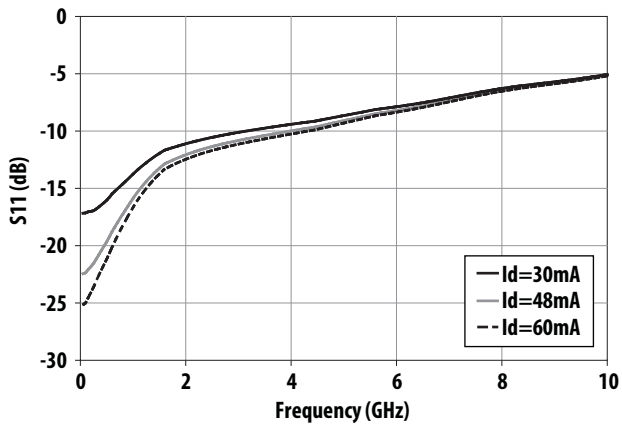


Figure 22.  $S_{11}$  vs Frequency and  $I_d$

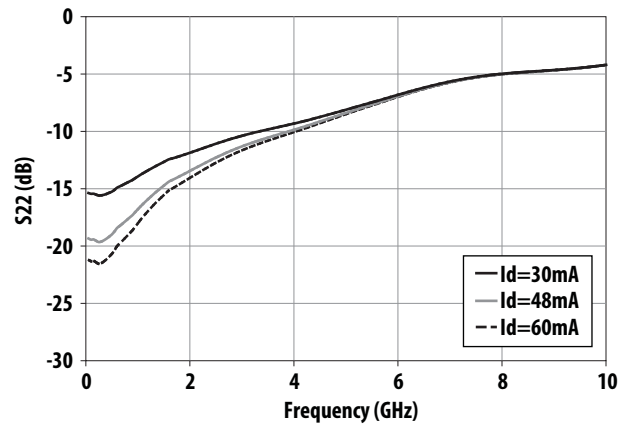


Figure 23.  $S_{22}$  vs Frequency and  $I_d$

**AVT-53663 Typical Scattering Parameters**  $T_A = 25^\circ\text{C}$ ,  $Z_0 = 50 \Omega$ ,  $I_d = 30 \text{ mA}$ , (unless specified otherwise)

Frequency GHz	S11			S21		S12		S22		K
	Mag	Angle	dB	Mag	Angle	Mag	Angle	Mag	Angle	
0.05	0.14	0.3	21.8	12.35	177.2	0.07	-0.9	0.17	-2.3	1.0
0.1	0.14	0.5	21.8	12.33	174.6	0.07	-1.4	0.17	-5.2	1.0
0.5	0.16	-3.1	21.5	11.95	153.6	0.06	-5.9	0.17	-27.2	1.0
0.9	0.19	-13.0	21.1	11.35	133.4	0.06	-10.1	0.19	-48.1	1.0
1.5	0.25	-32.7	20.2	10.25	104.4	0.06	-15.9	0.23	-79.5	1.1
2.0	0.28	-50.1	19.3	9.26	81.5	0.06	-20.4	0.26	-104.2	1.1
2.5	0.30	-69.3	18.3	8.27	59.8	0.06	-24.3	0.28	-125.7	1.2
3.0	0.31	-89.6	17.3	7.33	39.3	0.06	-27.7	0.30	-144.4	1.2
3.5	0.33	-110.5	16.2	6.47	19.7	0.06	-30.7	0.32	-161.8	1.3
4.0	0.34	-131.5	15.1	5.69	0.7	0.06	-33.4	0.34	-179.0	1.4
4.5	0.35	-152.0	13.9	4.97	-17.5	0.06	-36.0	0.37	164.0	1.4
5.0	0.37	-172.0	12.7	4.30	-35.1	0.06	-38.6	0.39	148.2	1.5
5.5	0.39	168.8	11.4	3.71	-51.9	0.06	-41.3	0.42	133.3	1.6
6.0	0.40	150.6	10.1	3.19	-67.9	0.06	-44.5	0.46	118.8	1.6
6.5	0.42	133.4	8.7	2.73	-83.1	0.06	-48.2	0.49	105.5	1.7
7.0	0.44	117.5	7.4	2.34	-97.4	0.07	-52.3	0.52	93.7	1.7
7.5	0.46	103.1	6.1	2.02	-110.8	0.07	-56.8	0.55	83.4	1.8
8.0	0.49	89.5	4.8	1.74	-123.5	0.07	-61.8	0.56	73.8	1.8
8.5	0.50	76.1	3.6	1.52	-135.9	0.08	-67.6	0.58	64.2	1.9
9.0	0.52	62.3	2.4	1.32	-148.2	0.08	-74.2	0.59	53.7	2.0
9.5	0.54	48.5	1.1	1.14	-160.4	0.08	-81.4	0.60	42.4	2.1
10.0	0.56	35.9	-0.2	0.98	-172.2	0.09	-88.9	0.62	30.7	2.3
10.5	0.58	25.1	-1.6	0.83	176.7	0.09	-96.2	0.64	19.1	2.4
11.0	0.60	16.1	-3.1	0.70	166.6	0.09	-103.0	0.67	8.8	2.6
11.5	0.62	8.1	-4.6	0.59	157.6	0.08	-109.3	0.70	0.0	2.8
12.0	0.64	0.4	-6.1	0.50	149.2	0.08	-115.2	0.73	-7.6	3.0
12.5	0.66	-7.6	-7.4	0.43	141.2	0.08	-121.3	0.74	-14.3	3.2
13.0	0.67	-16.1	-8.7	0.37	133.1	0.08	-127.8	0.75	-20.9	3.5
13.5	0.68	-25.4	-9.8	0.32	124.8	0.08	-135.0	0.75	-28.2	3.9
14.0	0.70	-35.4	-10.9	0.29	115.9	0.09	-143.0	0.74	-37.2	4.4
14.5	0.71	-45.6	-12.0	0.25	106.7	0.09	-151.6	0.74	-47.8	5.0
15.0	0.72	-55.3	-13.3	0.22	97.8	0.08	-160.3	0.74	-59.0	5.5
16.0	0.75	-70.1	-16.1	0.16	83.7	0.08	-174.3	0.78	-76.4	6.6
17.0	0.76	-80.6	-18.9	0.11	76.4	0.07	176.4	0.82	-84.6	7.7
18.0	0.77	-89.5	-21.1	0.09	73.0	0.07	168.7	0.84	-89.0	9.2
19.0	0.78	-99.2	-22.8	0.07	68.3	0.07	158.4	0.82	-98.8	12.0
20.0	0.80	-113.4	-24.7	0.06	59.8	0.07	142.7	0.80	-118.2	16.2

Notes:

1. S-parameters are measured on a CPWG line fabricated on 0.025 inch thick Rogers® RO4350 material. The input reference plane is at the end of the input lead. The output reference plane is at the end of the output lead.



**AVT-53663 Typical Scattering Parameters**  $T_A = 25^\circ\text{C}$ ,  $Z_0 = 50 \Omega$ ,  $I_d = 48 \text{ mA}$ , (unless specified otherwise)

Frequency GHz	S11			S21		S12		S22		K
	Mag	Angle	dB	Mag	Angle	Mag	Angle	Mag	Angle	
0.05	0.08	1.9	22.6	13.46	177.2	0.06	-0.1	0.11	-2.3	1.0
0.1	0.08	4.9	22.6	13.43	174.5	0.06	-1.0	0.11	-5.8	1.0
0.5	0.10	9.3	22.3	12.98	153.1	0.06	-5.3	0.11	-29.6	1.0
0.9	0.15	-0.6	21.8	12.28	132.5	0.06	-9.3	0.14	-51.6	1.0
1.5	0.22	-24.0	20.8	11.00	103.2	0.06	-14.8	0.18	-84.0	1.1
2.0	0.25	-43.0	19.9	9.86	80.3	0.06	-19.0	0.21	-108.9	1.1
2.5	0.27	-63.4	18.8	8.74	58.7	0.06	-22.8	0.24	-130.0	1.2
3.0	0.29	-84.8	17.7	7.71	38.3	0.06	-26.0	0.27	-148.0	1.2
3.5	0.30	-106.7	16.6	6.78	18.9	0.06	-28.8	0.30	-164.9	1.3
4.0	0.32	-128.5	15.5	5.95	0.1	0.06	-31.3	0.32	178.3	1.4
4.5	0.33	-149.6	14.3	5.19	-18.0	0.06	-33.7	0.35	161.5	1.4
5.0	0.35	-170.2	13.1	4.49	-35.5	0.06	-36.1	0.38	146.0	1.5
5.5	0.37	170.1	11.8	3.87	-52.1	0.06	-38.7	0.41	131.4	1.6
6.0	0.39	151.6	10.4	3.33	-68.1	0.06	-41.9	0.45	117.1	1.6
6.5	0.41	134.2	9.1	2.86	-83.2	0.06	-45.7	0.49	104.0	1.6
7.0	0.43	118.1	7.8	2.45	-97.5	0.07	-50.0	0.52	92.4	1.7
7.5	0.45	103.4	6.5	2.11	-110.9	0.07	-54.8	0.54	82.1	1.7
8.0	0.48	89.8	5.2	1.82	-123.6	0.07	-60.0	0.56	72.6	1.7
8.5	0.49	76.3	4.0	1.59	-136.0	0.08	-66.0	0.57	63.0	1.8
9.0	0.51	62.4	2.8	1.38	-148.4	0.08	-72.8	0.58	52.6	1.9
9.5	0.53	48.6	1.5	1.19	-160.6	0.09	-80.3	0.60	41.3	2.0
10.0	0.55	36.0	0.2	1.02	-172.4	0.09	-87.9	0.62	29.6	2.2
10.5	0.58	25.2	-1.2	0.87	176.6	0.09	-95.4	0.64	18.2	2.3
11.0	0.60	16.1	-2.7	0.73	166.5	0.09	-102.3	0.67	8.0	2.5
11.5	0.62	8.1	-4.2	0.62	157.4	0.09	-108.7	0.70	-0.7	2.7
12.0	0.63	0.4	-5.6	0.52	148.9	0.09	-114.7	0.73	-8.2	2.9
12.5	0.65	-7.6	-7.0	0.45	140.9	0.08	-120.9	0.74	-14.9	3.1
13.0	0.67	-16.1	-8.2	0.39	132.8	0.08	-127.5	0.75	-21.5	3.3
13.5	0.68	-25.4	-9.3	0.34	124.3	0.09	-134.7	0.75	-28.8	3.7
14.0	0.69	-35.5	-10.4	0.30	115.3	0.09	-142.8	0.74	-37.7	4.2
14.5	0.71	-45.7	-11.6	0.26	106.0	0.09	-151.5	0.74	-48.4	4.7
15.0	0.72	-55.3	-12.8	0.23	97.0	0.09	-160.2	0.74	-59.5	5.2
16.0	0.75	-70.2	-15.6	0.17	82.7	0.08	-174.3	0.78	-76.8	6.3
17.0	0.76	-80.7	-18.4	0.12	74.9	0.07	176.4	0.82	-84.9	7.4
18.0	0.77	-89.5	-20.6	0.09	71.0	0.07	168.7	0.83	-89.3	8.8
19.0	0.78	-99.3	-22.4	0.08	65.8	0.07	158.4	0.81	-99.1	11.6
20.0	0.80	-113.4	0.0	0.06	56.6	0.07	142.7	0.80	-118.5	15.7

Notes:

1. S-parameters are measured on a CPWG line fabricated on 0.025 inch thick Rogers® RO4350 material. The input reference plane is at the end of the input lead. The output reference plane is at the end of the output lead.

**AVT-53663 Typical Scattering Parameters**  $T_A = 25^\circ\text{C}$ ,  $Z_0 = 50 \Omega$ ,  $I_D = 60 \text{ mA}$ , (unless specified otherwise)

Frequency GHz	S11			S21		S12		S22		K
	Mag	Angle	dB	Mag	Angle	Mag	Angle	Mag	Angle	
0.05	0.06	3.9	22.8	13.81	177.2	0.06	-0.3	0.09	-2.5	1.0
0.1	0.06	8.5	22.8	13.78	174.5	0.06	-1.0	0.09	-5.9	1.0
0.5	0.09	16.0	22.5	13.31	153.0	0.06	-5.1	0.09	-30.4	1.0
0.9	0.13	5.1	22.0	12.58	132.4	0.06	-9.0	0.12	-52.7	1.0
1.5	0.21	-20.7	21.0	11.25	103.1	0.06	-14.4	0.17	-85.2	1.1
2.0	0.24	-40.3	20.1	10.07	80.2	0.06	-18.5	0.20	-110.1	1.1
2.5	0.26	-61.3	19.0	8.92	58.6	0.06	-22.3	0.23	-130.9	1.2
3.0	0.28	-83.1	17.9	7.87	38.3	0.06	-25.5	0.26	-148.7	1.2
3.5	0.29	-105.3	16.8	6.92	19.0	0.05	-28.2	0.29	-165.4	1.3
4.0	0.31	-127.4	15.7	6.07	0.3	0.05	-30.7	0.31	177.9	1.4
4.5	0.32	-148.7	14.5	5.30	-17.8	0.06	-33.0	0.34	161.2	1.4
5.0	0.34	-169.5	13.2	4.59	-35.2	0.06	-35.4	0.38	145.7	1.5
5.5	0.36	170.6	12.0	3.96	-51.9	0.06	-38.0	0.41	131.1	1.6
6.0	0.38	151.9	10.6	3.41	-67.8	0.06	-41.2	0.45	116.9	1.6
6.5	0.40	134.4	9.3	2.92	-83.0	0.06	-45.0	0.48	103.8	1.6
7.0	0.42	118.2	8.0	2.51	-97.3	0.07	-49.3	0.52	92.2	1.6
7.5	0.45	103.5	6.7	2.16	-110.7	0.07	-54.2	0.54	81.9	1.7
8.0	0.47	89.9	5.4	1.87	-123.5	0.08	-59.5	0.56	72.4	1.7
8.5	0.49	76.4	4.2	1.63	-135.9	0.08	-65.6	0.57	62.7	1.8
9.0	0.51	62.5	3.0	1.41	-148.3	0.08	-72.5	0.58	52.3	1.9
9.5	0.53	48.6	1.7	1.22	-160.5	0.09	-80.0	0.60	41.1	2.0
10.0	0.55	35.9	0.4	1.05	-172.3	0.09	-87.7	0.62	29.3	2.1
10.5	0.57	25.1	-1.0	0.89	176.6	0.09	-95.2	0.64	18.0	2.2
11.0	0.60	16.0	-2.5	0.75	166.5	0.09	-102.2	0.67	7.8	2.4
11.5	0.62	8.0	-4.0	0.63	157.3	0.09	-108.6	0.70	-0.9	2.6
12.0	0.63	0.3	-5.4	0.54	148.9	0.09	-114.6	0.72	-8.4	2.8
12.5	0.65	-7.6	-6.8	0.46	140.7	0.09	-120.8	0.74	-15.1	3.0
13.0	0.67	-16.2	-8.0	0.40	132.6	0.09	-127.4	0.75	-21.7	3.2
13.5	0.68	-25.5	-9.1	0.35	124.1	0.09	-134.7	0.75	-29.0	3.6
14.0	0.69	-35.5	-10.2	0.31	115.0	0.09	-142.8	0.74	-37.9	4.1
14.5	0.70	-45.7	-11.3	0.27	105.6	0.09	-151.5	0.73	-48.5	4.6
15.0	0.72	-55.3	-12.6	0.24	96.5	0.09	-160.3	0.74	-59.7	5.1
16.0	0.75	-70.3	-15.4	0.17	82.0	0.08	-174.3	0.78	-77.0	6.1
17.0	0.76	-80.7	-18.1	0.12	74.0	0.07	176.4	0.82	-85.0	7.2
18.0	0.77	-89.5	-20.3	0.10	69.8	0.07	168.6	0.83	-89.4	8.6
19.0	0.78	-99.3	-22.2	0.08	64.3	0.07	158.3	0.81	-99.2	11.3
20.0	0.79	-113.5	-24.1	0.06	54.8	0.07	142.6	0.79	-118.6	15.4

Notes:

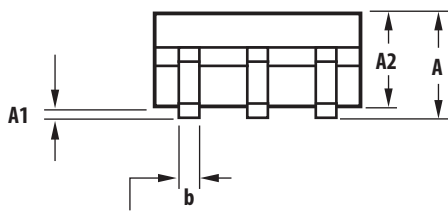
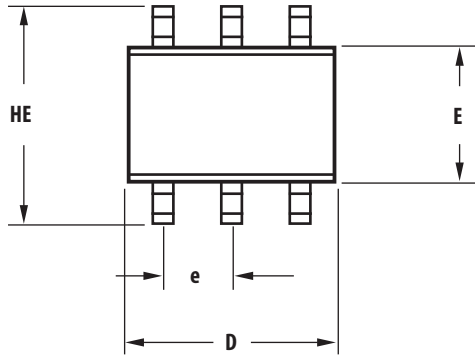
1. S-parameters are measured on a CPWG line fabricated on 0.025 inch thick Rogers® RO4350 material. The input reference plane is at the end of the input lead. The output reference plane is at the end of the output lead.

## Part Number Ordering Information

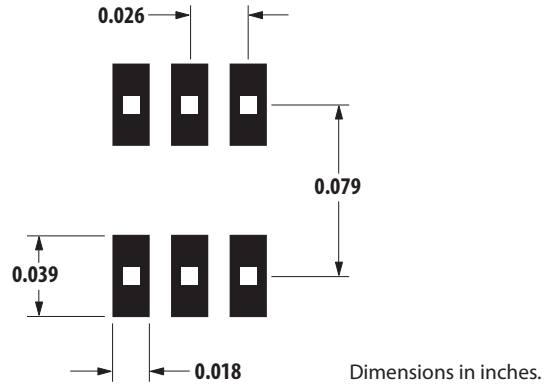
Part Number	No. of Devices	Container
AVT-53663-TR1G	3000	7" Reel
AVT-53663-BLKG	100	Antistatic bag

## Package Dimensions

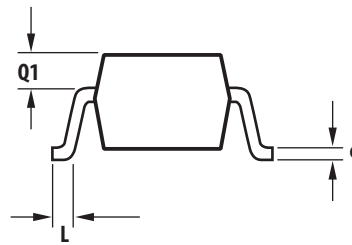
### Outline 63 (SOT-363/SC-70)



## Recommended PCB Pad Layout for Avago's SC70 6L/SOT-363 Products



Dimensions in inches.

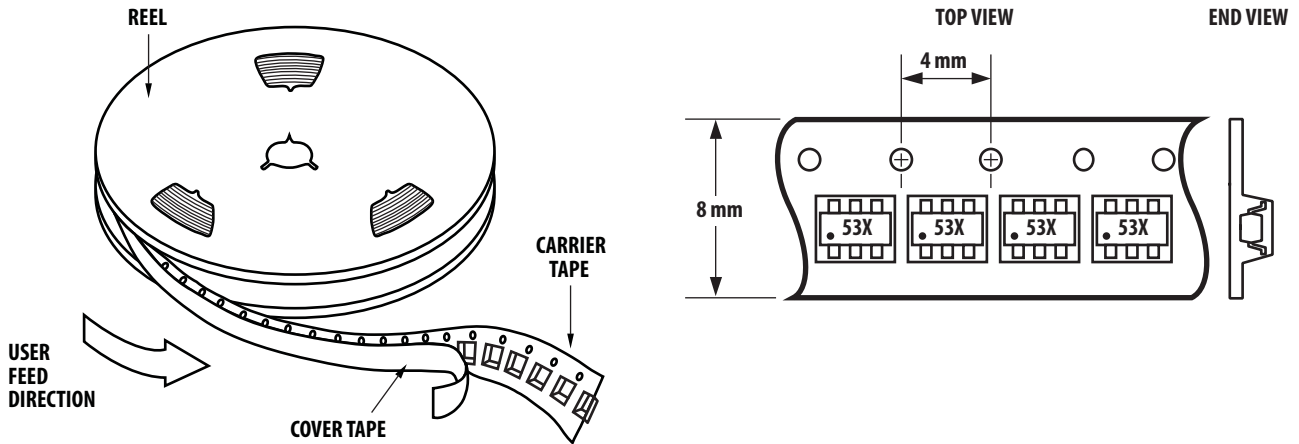


Symbol	Dimensions (mm)	
	Min	Max
E	1.15	1.35
D	1.80	2.25
HE	1.80	2.40
A	0.80	1.10
A2	0.80	1.00
A1	0.00	0.10
Q1	0.10	0.40
e	0.65	
b	0.15	0.30
c	0.08	0.25
L	0.10	0.46

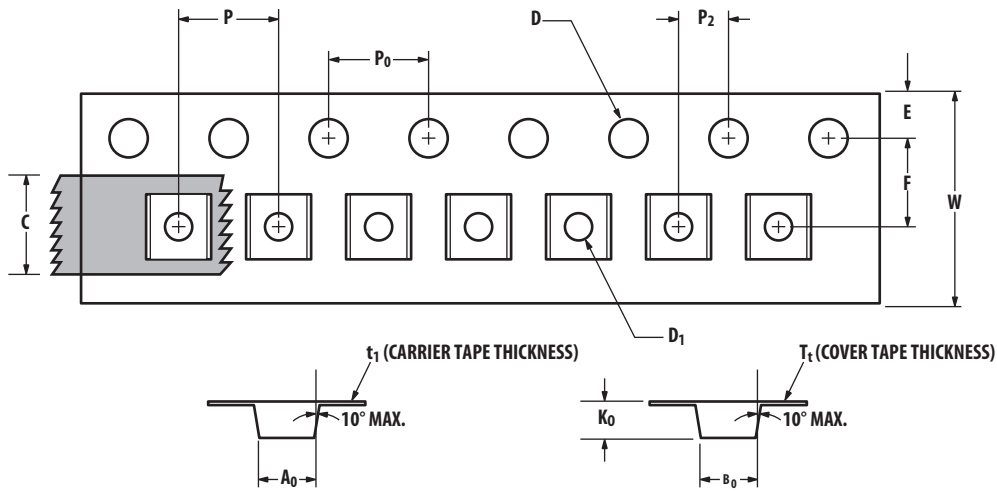
### Notes:

1. All dimensions are in mm.
2. Dimensions are inclusive of plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. All specifications comply to EIAJSC70.
5. Die is facing up for mold and facing down for trim/form, ie: reverse trim/form.
6. Package surface to be mirror finish. 0.650BCS.

## Device Orientation

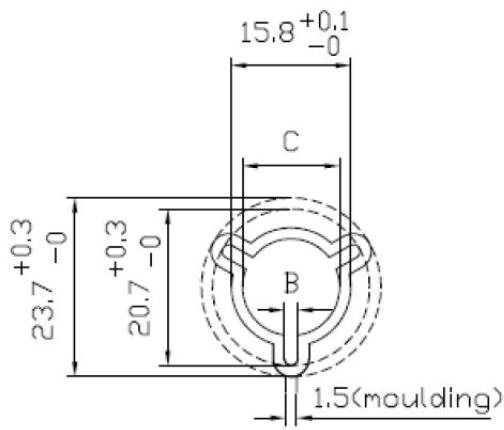
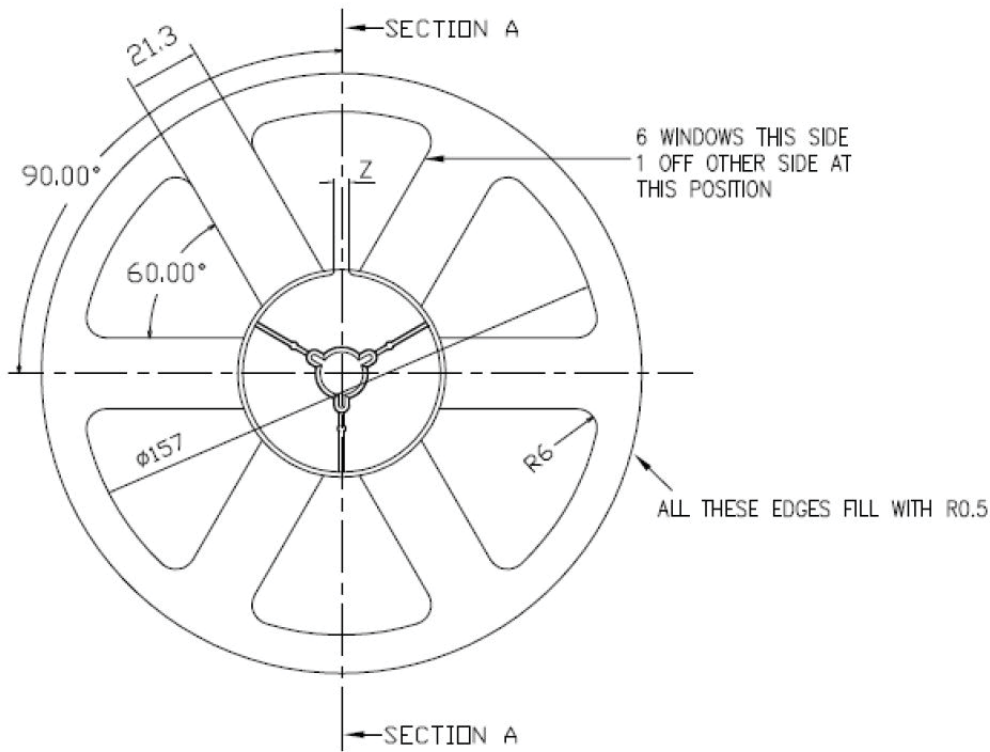


## Tape Dimensions and Product Orientation for Outline 63

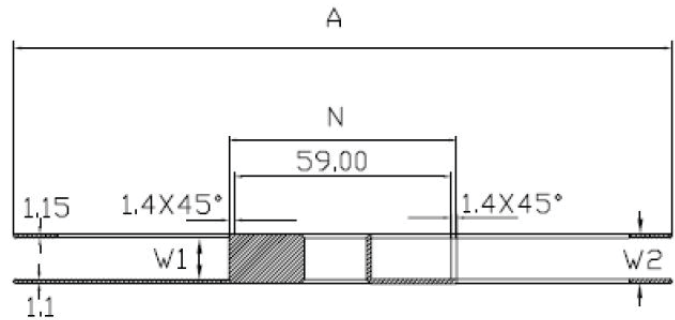


	DESCRIPTION	SYMBOL	SIZE (mm)	SIZE (INCHES)
CAVITY	LENGTH	A <sub>0</sub>	2.40 ± 0.10	0.094 ± 0.004
	WIDTH	B <sub>0</sub>	2.40 ± 0.10	0.094 ± 0.004
	DEPTH	K <sub>0</sub>	1.20 ± 0.10	0.047 ± 0.004
	PITCH	P	4.00 ± 0.10	0.157 ± 0.004
	BOTTOM HOLE DIAMETER	D <sub>1</sub>	1.00 + 0.25	0.039 + 0.010
PERFORATION	DIAMETER	D	1.55 ± 0.05	0.061 ± 0.002
	PITCH	P <sub>0</sub>	4.00 ± 0.10	0.157 ± 0.004
	POSITION	E	1.75 ± 0.10	0.069 ± 0.004
CARRIER TAPE	WIDTH	W	8.00 ± 0.30	0.315 ± 0.012
	THICKNESS	t <sub>1</sub>	0.254 ± 0.02	0.0100 ± 0.0008
COVER TAPE	WIDTH	C	5.4 ± 0.10	0.205 ± 0.004
	TAPE THICKNESS	T <sub>t</sub>	0.062 ± 0.001	0.0025 ± 0.0004
DISTANCE	CAVITY TO PERFORATION (WIDTH DIRECTION)	F	3.50 ± 0.05	0.138 ± 0.002
	CAVITY TO PERFORATION (LENGTH DIRECTION)	P <sub>2</sub>	2.00 ± 0.05	0.079 ± 0.002

**Reel Dimension 7 inch**



HUB DETAIL



SECTION A

For product information and a complete list of distributors, please go to our web site: [www.avagotech.com](http://www.avagotech.com)

Avago, Avago Technologies, and the A logo are trademarks of Avago Technologies in the United States and other countries.  
Data subject to change. Copyright © 2005-2011 Avago Technologies. All rights reserved.  
AV02-2359EN - September 29, 2011

